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<u>Vishay Semiconductor/Diodes Division</u> <u>ESH1B-M3/5AT</u>

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Vishay General Semiconductor

HALOGEN

FREE

Surface Mount Ultrafast Plastic Rectifier



DO-214AC (SMA)

PRIMARY CHARACTERISTICS					
I _{F(AV)}	1.0 A				
V _{RRM}	100 V, 150 V, 200 V				
t _{rr}	25 ns				
V _F	0.90 V				
T _J max.	175 °C				
Package	DO-214AC (SMA)				
Diode variations	Single die				

FEATURES

- Low profile package
- · Ideal for automated placement
- Glass passivated pellet chip junction
- Ultrafast recovery times for high efficiency
- Low forward voltage, low power loss
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in secondary rectification and freewheeling for ultrafast switching speeds AC/AC and DC/DC converters in high temperature conditions for both consumer applications.

MECHANICAL DATA

Case: DO-214AC (SMA)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test **Polarity:** Color band denotes cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	ESH1B	ESH1C	ESH1D	UNIT	
Device marking code		EHB	EHC	EHD		
Maximum repetitive peak reverse voltage	V_{RRM}	100	150	200	V	
Maximum RMS voltage	V_{RMS}	70	105	140	V	
Maximum DC blocking voltage	V_{DC}	100	150	200	V	
Maximum average forward rectified current at $T_L = 150 ^{\circ}\text{C}$	I _{F(AV)}	1.0			Α	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}	50			А	
Operating junction and storage temperature range	T _J , T _{STG}	-55 to +175			°C	

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ESH1B-M3, ESH1C-M3, ESH1D-M3

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT	
Maximum instantaneous forward voltage	I _F = 0.7 A		V _F ⁽¹⁾	0.87	V	
Waximum instantaneous forward voltage	I _F = 1 A		V_{F}	0.90		
Maximum DC reverse current at rated DC		T _A = 25 °C		1.0	μΑ	
blocking voltage		T _A = 125 °C	I _R	25		
Maximum reverse current	V _R = 20 V, T _J = 150 °C		I _R	50	μΑ	
Maximum reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$		t _{rr}	25	ns	
Typical reverse recovery time	$I_F = 0.6 \text{ A}, V_R = 30 \text{ V},$ $dI/dt = 50 \text{ A/}\mu\text{s}, I_{rr} = 10 \% I_{RM}$	T _J = 25 °C	t _{rr}	25	ns	
Typical reverse recovery time		T _J = 100 °C		35		
Typical stored charge	1F = 0.071, VR = 00 V,	T _J = 25 °C	Q _{rr}	10	nC	
		T _J = 100 °C		15		
Typical junction capacitance	4.0 V, 1 MHz		CJ	25	pF	

Note

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	ESH1B	ESH1C	ESH1D	UNIT
Typical thermal variations	R _{0JA} (1)	85			°C/W
Typical thermal resistance	R _{0JL} (1)	30		C/VV	

Note

⁽¹⁾ Units mounted on PCB with 5.0 mm x 5.0 mm (0.013 mm thick) land areas

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
ESH1D-M3/61T	0.064	61T	1800	7" diameter plastic tape and reel	
ESH1D-M3/5AT	0.064	5AT	7500	13" diameter plastic tape and reel	



ESH1B-M3, ESH1C-M3, ESH1D-M3

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

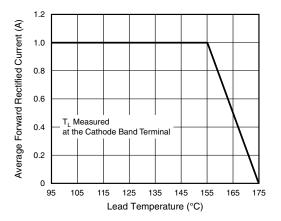


Fig. 1 - Maximum Forward Current Derating Curve

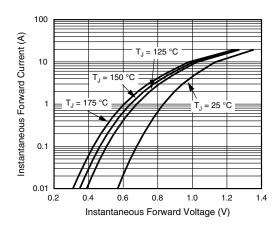


Fig. 4 - Typical Instantaneous Forward Characteristics

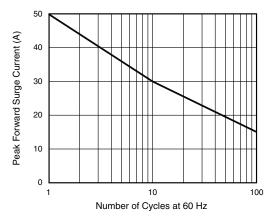


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

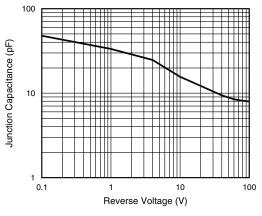


Fig. 5 - Typical Junction Capacitance

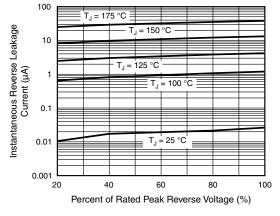


Fig. 3 - Typical Reverse Leakage Characteristics

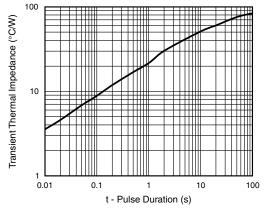


Fig. 6 - Typical Transient Thermal Impedance

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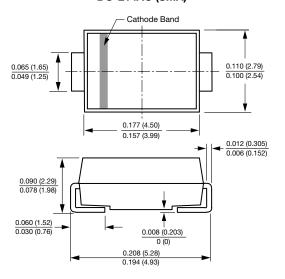




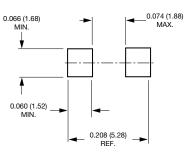
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

DO-214AC (SMA)



Mounting Pad Layout





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